L Number	Hits	Search Text	DB	Time stamp
4	1391	349/149	USPAT;	2003/11/17 10:17
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
5	63808	terminal near3 electrode	USPAT;	2003/11/17 10:20
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	225	240/140 and (harminal near) electrode)	IBM_TDB	2003/11/17 10:17
6	335	349/149 and (terminal near3 electrode)	USPAT; US-PGPUB;	2003/11/17 10.17
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
7	99	((liquid near3 crystal) or lcd) and ((tft or (thin	USPAT;	2003/11/17 10:19
'	, ,	near3 film near3 transistor)) near6 substrate) and	US-PGPUB;	2003/11/17 10/13
		(pixel near3 electrode) and switch\$4 and ((source	EPO; JPO;	
		and gate) near4 line) and ((display and terminal)	DERWENT;	
		near5 area)	IBM_TDB	
8	65	(terminal near3 electrode) and (((liquid near3	USPAT;	2003/11/17 10:19
		crystal) or lcd) and ((tft or (thin near3 film near3	US-PGPUB;	
		transistor)) near6 substrate) and (pixel near3	EPO; JPO;	
		electrode) and switch\$4 and ((source and gate)	DERWENT;	
		near4 line) and ((display and terminal) near5	IBM_TDB	
		area))		
9	4	((terminal near3 electrode) and (((liquid near3	USPAT;	2003/11/17 10:19
		crystal) or lcd) and ((tft or (thin near3 film near3	US-PGPUB;	
		transistor)) near6 substrate) and (pixel near3	EPO; JPO;	
		electrode) and switch\$4 and ((source and gate)	DERWENT;	
		near4 line) and ((display and terminal) near5	IBM_TDB	
11	12497	area))) and 349/149 terminal adj electrode	USPAT;	2003/11/17 10:20
*	12497	terrilliar auf electrode	US-PGPUB;	2003/11/17 10.20
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
12	8	(terminal adj electrode) and ((terminal near3	USPAT;	2003/11/17 10:21
	_	electrode) and (((liquid near3 crystal) or lcd) and	US-PGPUB;	, ,
		((tft or (thin near3 film near3 transistor)) near6	EPO; JPO;	
		substrate) and (pixel near3 electrode) and	DERWENT;	
		switch\$4 and ((source and gate) near4 line) and	IBM_TDB	
		((display and terminal) near5 area)))		
13	8	(terminal adj electrode) and (((liquid near3 crystal)	USPAT;	2003/11/17 10:21
		or lcd) and ((tft or (thin near3 film near3	US-PGPUB;	
		transistor)) near6 substrate) and (pixel near3	EPO; JPO;	
		electrode) and switch\$4 and ((source and gate)	DERWENT;	
		near4 line) and ((display and terminal) near5	IBM_TDB	
	1282	area)) 349/149	USPAT;	2003/05/15 15:24
-	1202	JT <i>3 </i> 143 	US-PGPUB;	2003/03/13 13.24
			EPO; JPO;	
		·	DERWENT;	
			IBM_TDB	
-	1234	((liquid near3 crystal) or lcd) and (tft or (thin	USPAT;	2003/05/15 16:29
	 ·	near3 film near3 transistor)) and substrate and	US-PGPUB;	, , ======
		electrode and switch\$4 and ((source and gate)	EPO; JPO;	
		near4 line)	DERWENT;	
			IBM_TDB	

			LICDAT	2002/05/15 16:20
-	747	(((liquid near3 crystal) or lcd) and (tft or (thin	USPAT;	2003/05/15 16:29
		near3 film near3 transistor)) and substrate and	US-PGPUB;	
		electrode and switch\$4 and ((source and gate)	EPO; JPO;	
		near4 line)) and terminal	DERWENT;	
	·		IBM_TDB	
_	50	((liquid near3 crystal) or lcd) and (tft or (thin	USPAT;	2003/05/16 11:32
		near3 film near3 transistor)) and (pixel near3	US-PGPUB;	
		electrode) and switch\$4 and ((gate and source and	EPO; JPO;	İ
		metal\$4) near3 line) and insulat\$3	DERWENT;	
		metaly if near b miles and mediates	IBM_TDB	
	35	((liquid near3 crystal) or lcd) and (tft or (thin	USPAT;	2003/05/16 11:36
	33	near3 film near3 transistor)) and (pixel near3	US-PGPUB;	2000, 00, 20 22.20
		electrode) and switch\$4 and ((gate and source and	EPO; JPO;	
		metal\$4) near3 line) and insulat\$3 and hole	DERWENT;	
		metals filears line; and misulates and note	IBM TDB	
	33	(/liquid manua amustal) are lad) and (tft or (thin	USPAT:	2003/05/16 11:52
-	33	((,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	,	2003/03/10 11.32
		near3 film near3 transistor)) and (pixel near3	US-PGPUB;	
		electrode) and switch\$4 and ((gate and source and	EPO; JPO;	
		metal\$4) near3 line) and insulat\$3 and (contact	DERWENT;	
		near4 hole)	IBM_TDB	